SN54ACT533供应商

SN54ACT533, SN74ACT533 **OCTAL TRANSPARENT D-TYPE LATCHES** WITH 3-STATE OUTPUTS

SN54ACT533 ... J OR W PACKAGE SN74ACT533 ... DB, DW, N, OR PW PACKAGE

(TOD VIEW)

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- Inputs Are TTL-Voltage Compatible
- **3-State Inverting Outputs Drive Bus Lines** Directly
- **EPIC[™]** (Enhanced-Performance Implanted CMOS) 1-µm Process
- **Package Options Include Plastic** Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Chip Carriers (FK) and Flatpacks (W), and Standard Plastic (N) and Ceramic (J) DIPs

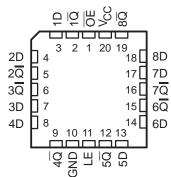
description

The 'ACT533 devices are octal transparent D-type latches with 3-state outputs. When the latch-enable (LE) input is high, the \overline{Q} outputs follow the complements of the data (D) inputs. When LE is taken low, the \overline{Q} outputs are latched at the inverted levels set up at the D inputs.

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pullup components.

		E v v)	
	1 2 3 4 5 6 7 8 9	18 17 16 15 14 13	V _{CC} 8Q 8D 7D 7Q 6Q 5D 5Q
GND	10	11] LE

SN54ACT533 ... FK PACKAGE (TOP VIEW)



OE does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

The SN54ACT533 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74ACT533 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE (each latch)									
	INPUTS		OUTPUT						
OE	LE	D	Q						
L	Н	Н	L						
L	Н	L	н						
L	L	Х	Q ₀ Z						
н	Х	Х	Z						



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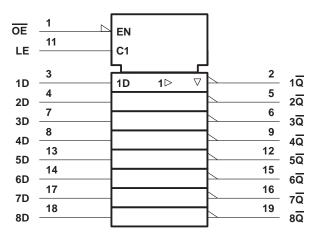
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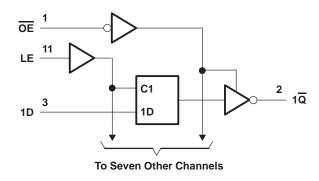
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logic symbol[†]



logic diagram (positive logic)



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage range, V _{CC}		–0.5 V to 7 V
Input voltage range, VI (see Note 1)		–0.5 V to V _{CC} + 0.5 V
Output voltage range, VO (see Note 1)		–0.5 V to V _{CC} + 0.5 V
Input clamp current, I_{IK} (V _I < 0 or V _I > V _{CC})		±20 mA
Output clamp current, I_{OK} (V _O < 0 or V _O > V _{CO}	c)	±20 mA
Continuous output current, $I_O (V_O = 0 \text{ to } V_{CC})$	-	±50 mA
Continuous current through V _{CC} or GND		±200 mA
Package thermal impedance, θ_{JA} (see Note 2):		
	DW package	58°C/W
	N package	
	PW package	
Storage temperature range, T _{stg}		–65°C to 150°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.



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recommended operating conditions (see Note 3)

		SN54ACT533		SN74ACT533		UNIT
		MIN	MAX	MIN	MAX	UNIT
VCC	Supply voltage	4.5	5.5	4.5	5.5	V
VIH	High-level input voltage	2	Ŋ	2		V
VIL	Low-level input voltage		0.8		0.8	V
VI	Input voltage	0	Vcc	0	VCC	V
Vo	Output voltage	0	Vcc	0	VCC	V
ЮН	High-level output current	200	-24		-24	mA
IOL	Low-level output current	20%	24		24	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Q 0	8	0	8	ns/V
TA	Operating free-air temperature	-55	125	-40	85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS	N.	т	Δ = 25°C	;	SN54A	CT533	SN74ACT533		
PARAMETER	TEST CONDITIONS	Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
		4.5 V	4.4	4.49		4.4		4.4		
	I _{OH} = -50 μA	5.5 V	5.4	5.49		5.4		5.4		
Vou	1011 - 24 mA	4.5 V	3.86			3.7		3.76		V
VOH	I _{OH} = -24 mA	5.5 V	4.86			4.7		4.76		v
	I _{OH} = -50 mA [†]	5.5 V				3.85				
	$I_{OH} = -75 \text{ mA}^{\dagger}$	5.5 V					Ŋ	3.85		
	I _{OL} = 50 μA	4.5 V			0.1		0.1		0.1	V
		5.5 V			0.1		0.1		0.1	
Ver	I _{OL} = 24 mA	4.5 V			0.36	7	0.5		0.44	
V _{OL}		5.5 V			0.36	20	0.5		0.44	
	$I_{OL} = 50 \text{ mA}^{\dagger}$	5.5 V				202	1.65			
	$I_{OL} = 75 \text{ mA}^{\dagger}$	5.5 V				4			1.65	
IOZ	$V_{O} = V_{CC}$ or GND	5.5 V			±0.25		±5		±2.5	μA
l	$V_I = V_{CC}$ or GND	5.5 V			±0.1		±1		±1	μΑ
ICC	$V_{I} = V_{CC} \text{ or GND}, \qquad I_{O} = 0$	5.5 V			4		80		40	μA
∆ICC‡	One input at 3.4 V, Other inputs at GND or V _{CC}	5.5 V		0.6			1.6		1.5	mA
Ci	$V_I = V_{CC}$ or GND	5 V		4.5						pF

[†] Not more than one output should be tested at a time, and the duration of the test should not exceed 2 ms.

[‡]This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

timing requirements over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

		T _A = 25°C		T _A = 25°C SN54ACT533 SN7		SN74A	SN74ACT533	
		MIN	MAX	MIN	MAX	MIN	MAX	UNIT
tw	Pulse duration, LE high	5		7.5	12 C	6		ns
t _{su}	Setup time, data before LE \downarrow	3		5.5	Nr	4		ns
t _h	Hold time, data after LE \downarrow	2		4		2.5		ns

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switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	T _A = 2	25°C	SN54A	CT533	SN74A	CT533	UNIT
FARAIVIETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
^t PLH	D	Q	2.5	10.5	1.5	13	2	11.5	ns
^t PHL	D	Q	2.5	10	1.5	12.5	2	11	115
^t PLH	LE	Q	2.5	10.5	1.5	A 13	2	11.5	ns
^t PHL	LL	Q	2.5	10.5	1.5	2 13	2	11.5	115
^t PZH	OE	0	2	10	5	12.5	1.5	11	20
^t PZL	ÛE	Q	2	10	Q1	12.5	1.5	11	ns
^t PHZ	OE	Q	2	10	<u>x</u> 1	12.5	1.5	11	ns
^t PLZ	UE	Ŷ	2	10	1	12.5	1.5	11	115

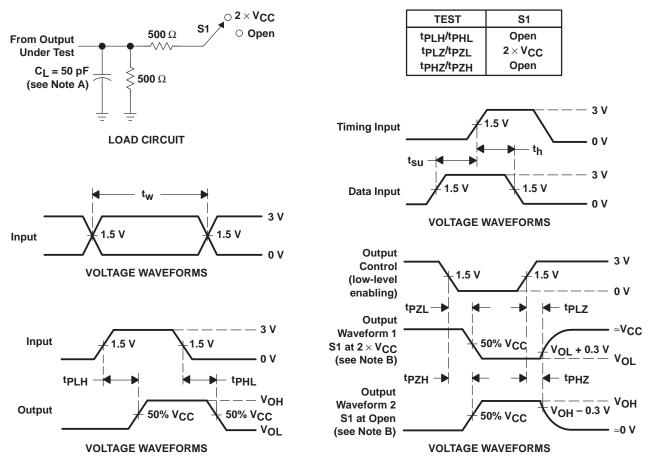
operating characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd} Power dissipation capacitance	$C_L = 50 \text{ pF}, \text{ f} = 1 \text{ MHz}$	40	pF

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PARAMETER MEASUREMENT INFORMATION

- NOTES: A. CL includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_Q = 50 Ω , t_f \leq 2.5 ns, t_f \leq 2.5 ns.
 - D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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